

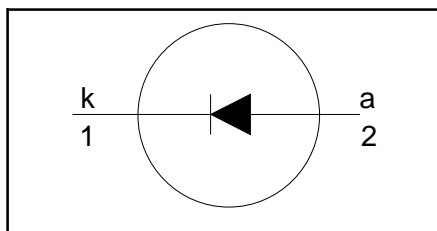
**Rectifier diode  
ultrafast, low switching loss**

**BYC10-600**

**FEATURES**

- Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

**SYMBOL**



**QUICK REFERENCE DATA**

$V_R = 600\text{ V}$
$V_F \leq 1.8\text{ V}$
$I_{F(AV)} = 10\text{ A}$
$t_{rr} = 19\text{ ns (typ)}$

**APPLICATIONS**

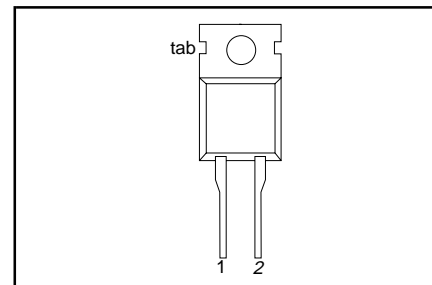
- Active power factor correction
- Half-bridge lighting ballasts
- Half-bridge/ full-bridge switched mode power supplies.

The BYC10-600 is supplied in the SOD59 (TO220AC) conventional leaded package.

**PINNING**

PIN	DESCRIPTION
1	cathode
2	anode
tab	cathode

**SOD59 (TO220AC)**



**LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	Peak repetitive reverse voltage		-	600	V
$V_{RWM}$	Crest working reverse voltage		-	600	V
$V_R$	Continuous reverse voltage	$T_{mb} \leq 114\text{ }^\circ\text{C}$	-	500	V
$I_{F(AV)}$	Average forward current	$\delta = 0.5$ ; with reapplied $V_{RRM(max)}$ ; $T_{mb} \leq 78\text{ }^\circ\text{C}^1$	-	10	A
$I_{FRM}$	Repetitive peak forward current	$\delta = 0.5$ ; with reapplied $V_{RRM(max)}$ ; $T_{mb} \leq 78\text{ }^\circ\text{C}^1$	-	20	A
$I_{FSM}$	Non-repetitive peak forward current.	$t = 10\text{ ms}$ $t = 8.3\text{ ms}$ sinusoidal; $T_j = 150\text{ }^\circ\text{C}$ prior to surge with reapplied $V_{RWM(max)}$	-	65	A
$T_{stg}$	Storage temperature		-40	150	$^\circ\text{C}$
$T_j$	Operating junction temperature		-	150	$^\circ\text{C}$

**THERMAL RESISTANCES**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base		-	-	2	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	in free air.	-	60	-	K/W

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**ELECTRICAL CHARACTERISTICS**

$T_j = 25\text{ }^\circ\text{C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 10\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	1.4	1.8	V
		$I_F = 20\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	1.7	2.3	V
		$I_F = 10\text{ A}; V_R = 600\text{ V}$	-	2.0	2.8	V
$I_R$	Reverse current	$V_R = 600\text{ V}; T_j = 100\text{ }^\circ\text{C}$	-	9	200	$\mu\text{A}$
$t_{rr}$	Reverse recovery time	$I_F = 10\text{ A to } V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}$	-	1.1	3.0	ns
$t_{rr}$	Reverse recovery time	$I_F = 10\text{ A to } V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 125\text{ }^\circ\text{C}$	-	19	-	ns
$I_{rrm}$	Peak reverse recovery current	$I_F = 10\text{ A to } V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 125\text{ }^\circ\text{C}$	-	32	40	ns
$V_{fr}$	Forward recovery voltage	$I_F = 10\text{ A}; dI_F/dt = 100\text{ A}/\mu\text{s}$	-	9.5	12	A
			-	8	11	V

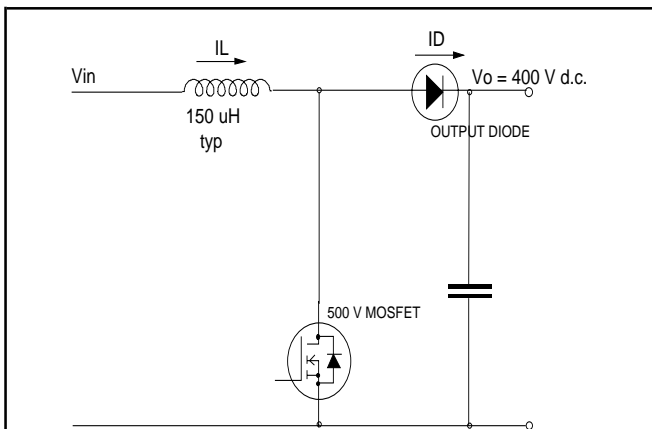


Fig.1. Typical application, output rectifier in boost converter power factor correction circuit. Continuous conduction, mode where the transistor turns on whilst forward current is still flowing in the diode.

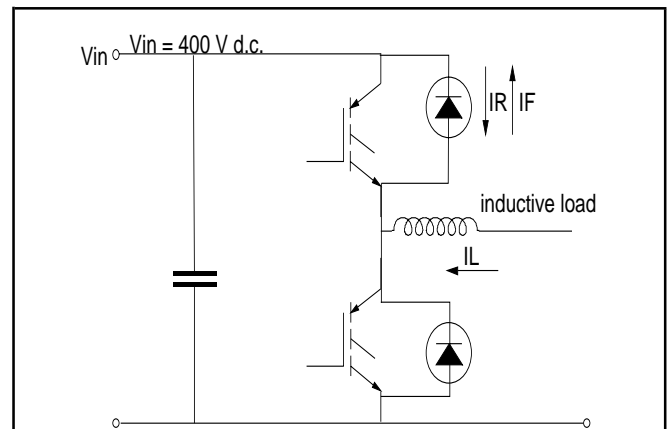
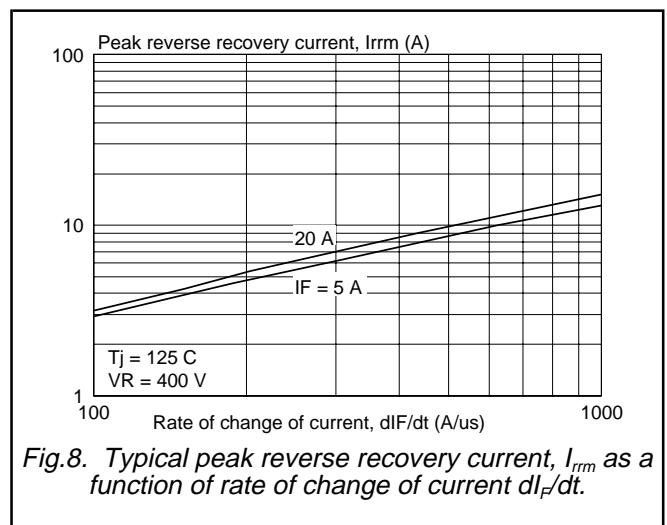
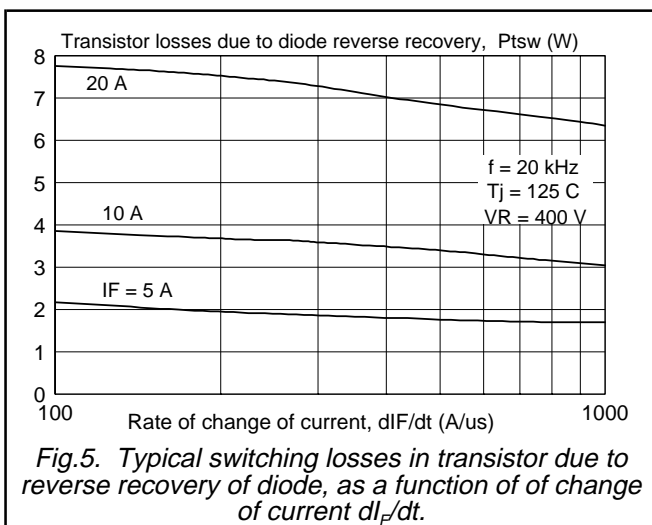
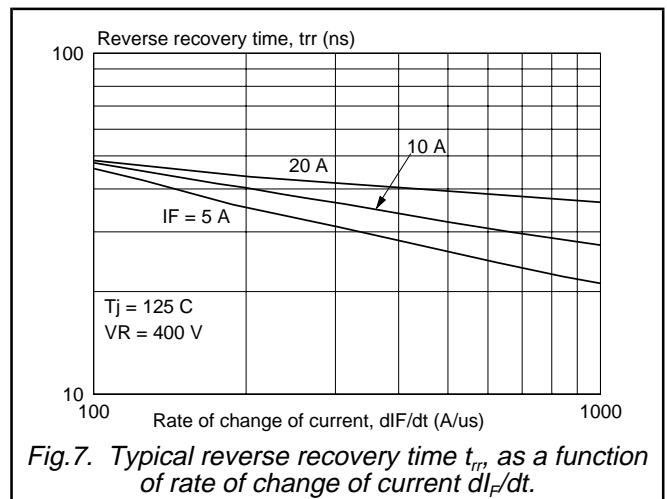
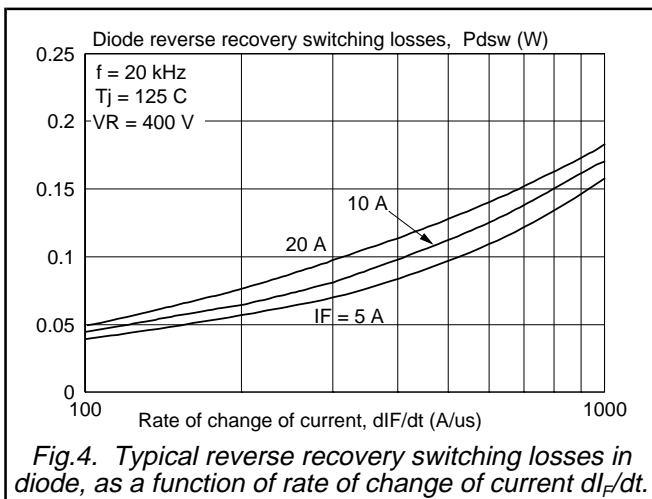
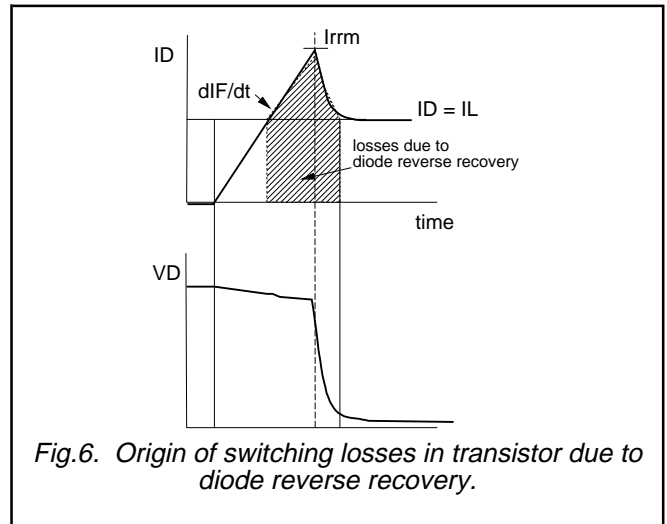
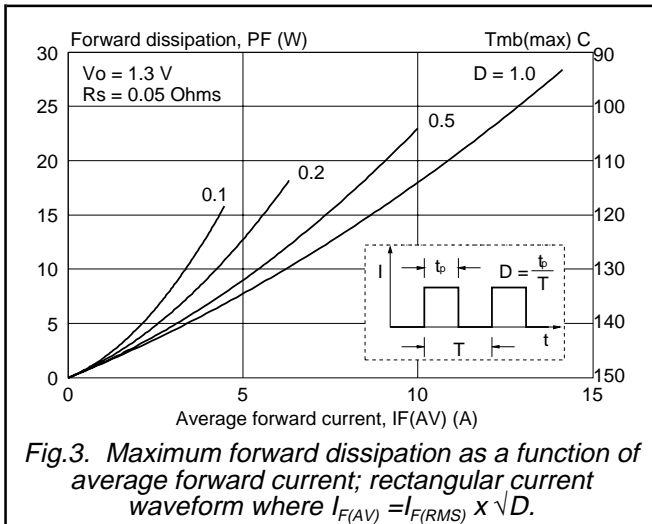


Fig.2. Typical application, freewheeling diode in half bridge converter. Continuous conduction mode, where each transistor turns on whilst forward current is still flowing in the other bridge leg diode.

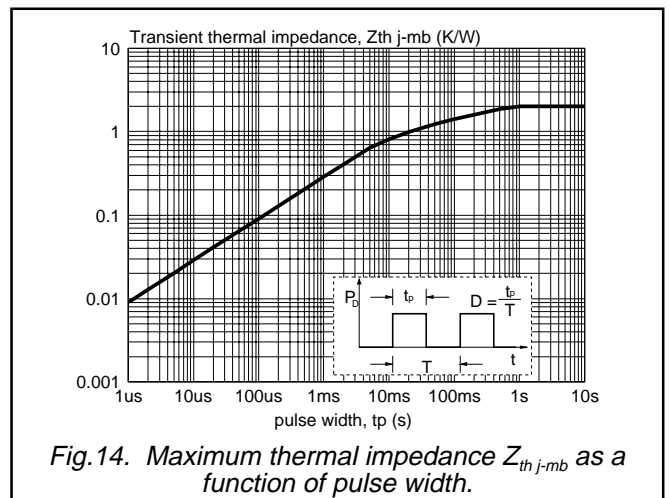
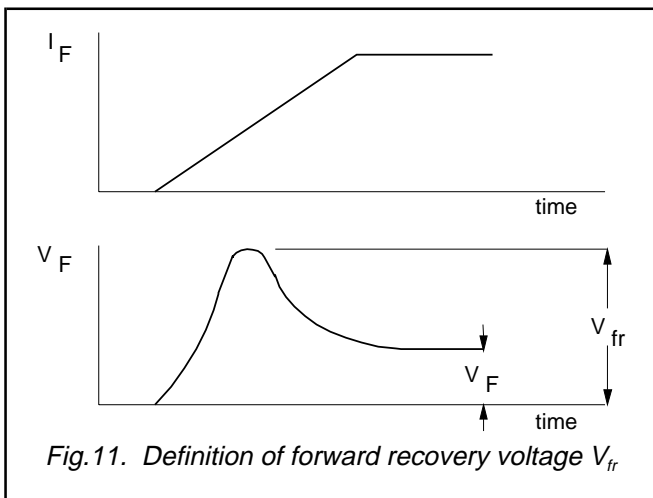
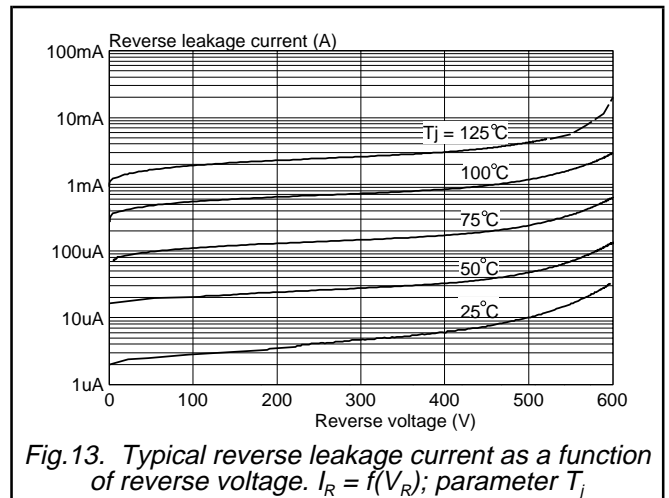
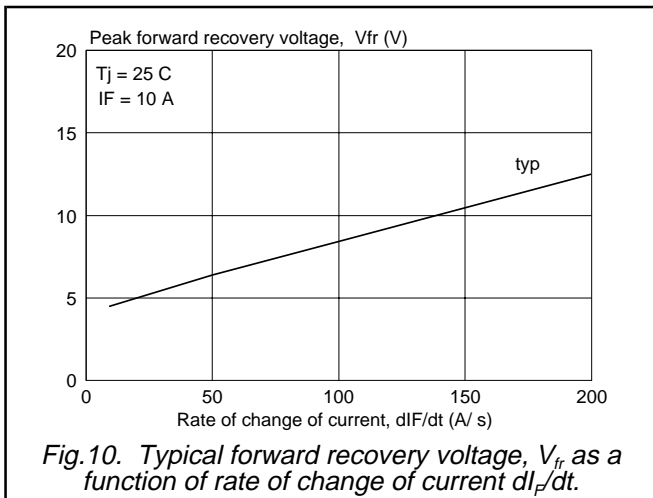
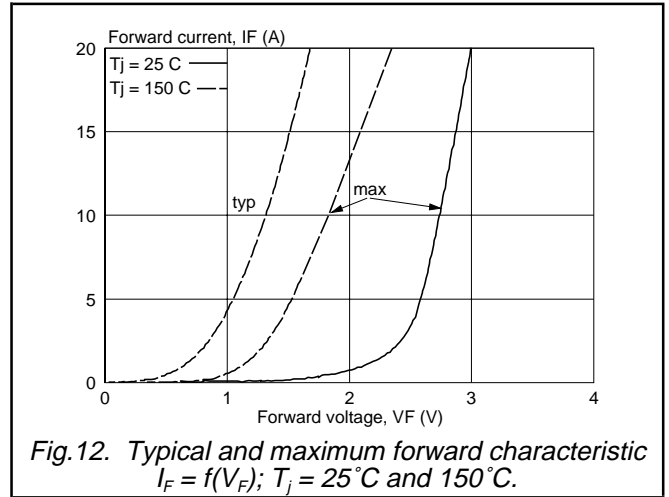
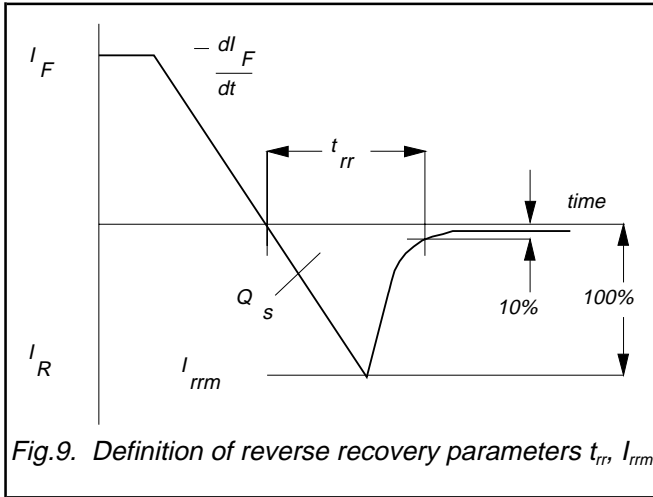
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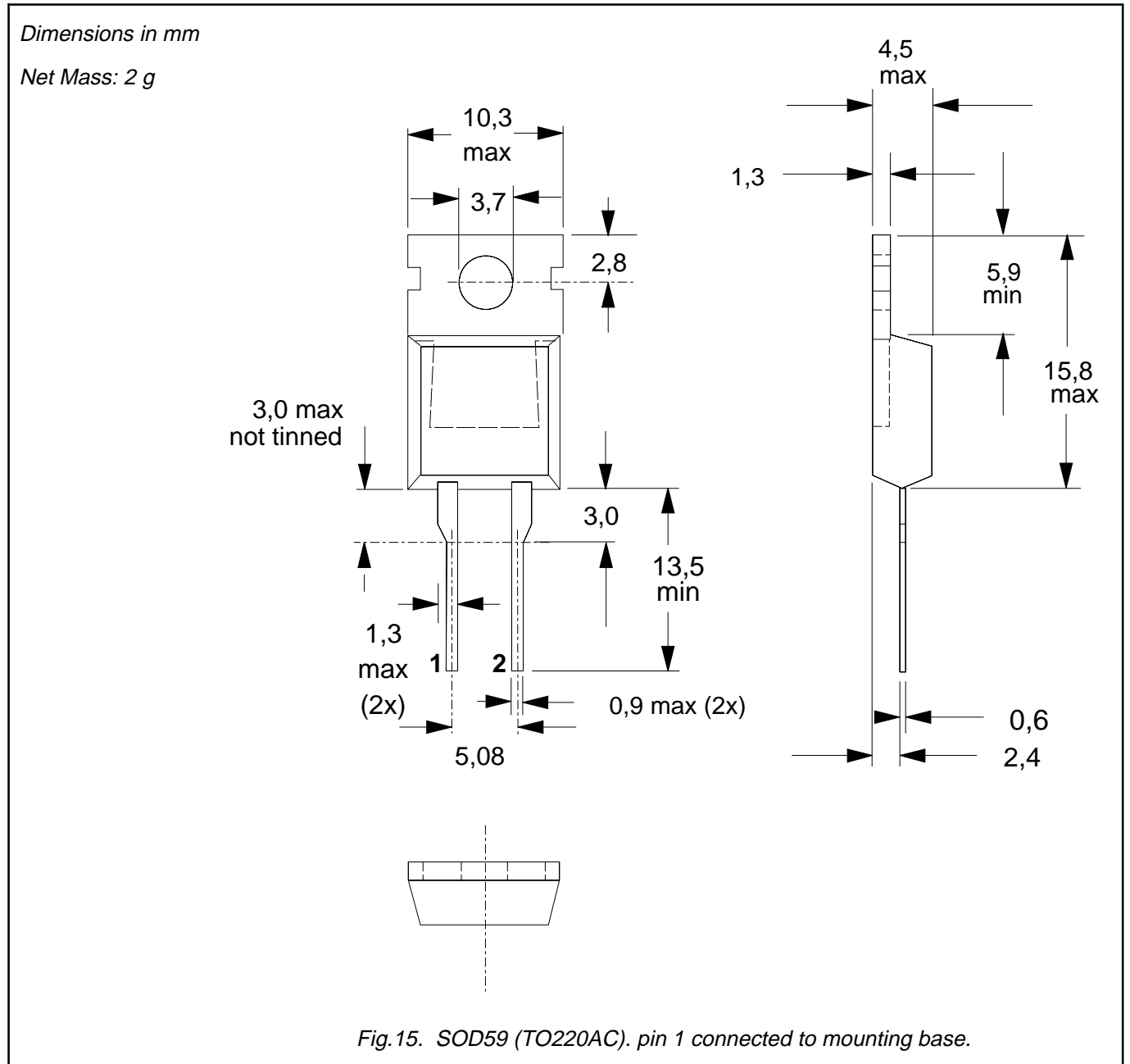
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**MECHANICAL DATA**



**Notes**

1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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**DEFINITIONS**

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	
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